OP230 Series

Obsolete (OP231W)

Features:

- Focused and non-focused optical light pattern
- Enhanced temperature range
- TO-46 hermetically sealed package
- Mechanically and spectrally matched to other Optek devices
- Choice of power ranges
- Choice of narrow or wide irradiance pattern



Description:

Each device in this series is a gallium aluminum arsenide (GaAlAs) infrared emitting diode, mounted in a hermetic metal TO-46 housing. The gallium aluminum arsenide feature provides a higher radiated output than gallium arsenide at the same forward current.

Each **OP231**, **OP232**, **OP233**, **OP234** and **OP235** device is lensed to provide a narrow beam angle (18°) between half power points. The 890 nm wavelength closely matches the spectral response of silicon phototransistors, while the narrow beam angle – combined with the specified radiant intensity of the OP231 series – facilitates easy design in beam interrupt applications in conjunction with the OP800 or OP598 series photosensors. *The OP231 series is mechanically and spectrally matched to OP800*, *OP593 and OP598 phototransistors*.

Each **OP232W**, **OP233W**, **OP234W** and **OP235W** device is lensed to provide a wide beam angle (50°) between half power points. The 890 nm wavelength closely matches the spectral response of silicon photo-transistors, while the wide beam angle provides relatively even illumination over a large area. The OP23xW series is mechanically and spectrally matched to the OP800WSL and OP830SL series devices.

Please refer to Application Bulletins 208 and 210 for additional design information and reliability (degradation) data.

Custom electrical, wire and cabling and connectors are available. Contact your local representative or OPTEK for more information.

Applications:

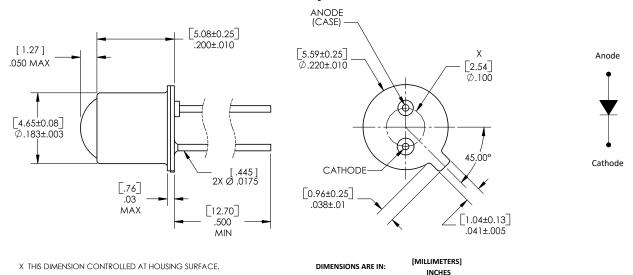
- Non-contact reflective object sensor
- Assembly line automation
- Machine automation
- Machine safety
- End of travel sensor
- Door sensor

Ordering Information							
Part Number	LED Peak Wavelength	Output Power (mW/cm²) Min / Max	Total Beam Angle	Lead Length			
OP231		1.5 / NA		0.50"			
OP232	890 nm	2.0 / 6.0					
OP233		3.0 / NA	18°				
OP234	9F0 nm	5.0 / NA					
OP235	850 nm	6.0 / NA					
OP231W (Obsolete)		1.5 / NA					
OP232W	890 nm	3.5 / 7.0					
OP233W		5.0 / NA	50°				
OP234W	9F0 nm	5.0 / NA					
OP235W	850 nm	6.0 / NA					

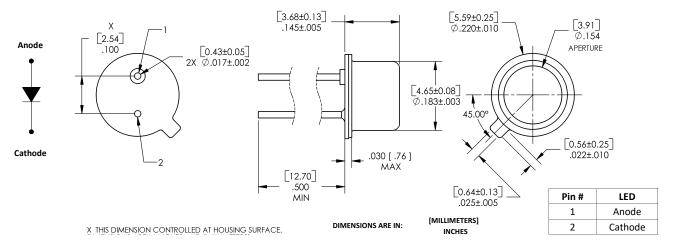
OP230 Series
Obsolete (OP231W)



Electrical Specifications



OP232W, OP233W, OP234W, OP235W



Absolute Maximum Ratings (T_A = 25° C unless otherwise noted)

Storage Temperature Range	-65° C to +150° C
Operating Temperature Range	-65° C to +125° C
Reverse Voltage	2.0 V
Continuous Forward Current	100 mA
Peak Forward Current	10.0 A
Lead Soldering Temperature [1/16 inch (1.6 mm) from case for 5 seconds with soldering iron]	260° C ⁽¹⁾
Power Dissipation	200 mW ⁽²⁾

OP230 Series

Obsolete (OP231W)



Electrical Specifications

Electrical Characteristics (T_A = 25° C unless otherwise noted)

SYMBOL	PARAMETER	MIN	TYP	MAX	UNITS	TEST CONDITIONS			
Input Diode									
E _{e(APT)}	Apertured Radiant Incidence OP231 OP232 OP233 OP234 OP235			- 6.0 - -	mW/ cm²	I _F = 100 mA ⁽³⁾⁽⁴⁾ Aperture = 0.250" Distance = 1.429"			
	OP232W OP233W OP234W OP235W	3.5 5.0 5.0 6.0		7.0 - -	mW/ cm²	I _F = 100 mA ⁽³⁾⁽⁴⁾ Aperture = 0.250" Distance = 0.466"			
Po	Radiant Power Output OP231 OP232 OP233	- - -	6.0 8.0 10.0	- - -	mW	I _F = 100 mA ⁽³⁾			
V _F	Forward Voltage	-	-	2.0	V	I _F = 100 mA ⁽³⁾			
I _R	Reverse Current	-	-	100	μΑ	V _R = 2.0 V			
λ_{P}	Wavelength at Peak Emission OP231, OP232, OP233 OP234, OP235	-	890 850	-	nm	I _F = 10 mA			
β	Spectral Bandwidth between Half Power Points	-	80	-	nm	I _F = 10 mA			
$\Delta \lambda_P / \Delta T$	Spectral Shift with Temperature	-	+0.30	-	nm/° C	I _F = Constant			
Өнр	Emission Angle at Half Power Points OP231 - OP235 OP231W - OP235W		18 50		Degree	I _F = 100 mA			
t _r	Output Rise Time	-	500	-	ns	I _{F(PK)} = 100 mA, PW = 10 μs, and D.C. = 10.0 %			
t _f	Output Fall Time	-	250	-	ns				

Notes:

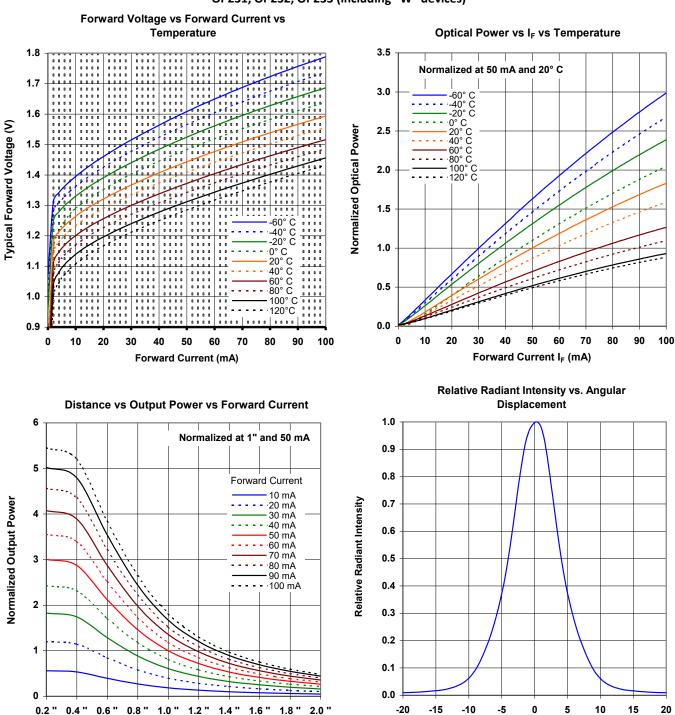
- 1. RMA flux is recommended. Duration can be extended to 10 seconds maximum when flow soldering.
- 2. Derate linearly 2.0 mW/° C above 25° C.
- 3. Measurement made with 100 μ s pulse measured at the trailing edge of the pulse with a duty cycle of 0.1 % and an I_F = 100 mA.
- 4. For the OP231 series, E_{E(APT)} is a measurement of the average radiant intensity within the cone formed by the measurement surface, a radius of 1.429" (36.30 mm) measured from the lens side of the tab to the sensing surface and a sensing surface of 0.250" (6.35 mm) in diameter forming a 10° cone. For the OP23xW series, E_{E(APT)} is a measurement of the average radiant intensity within the cone formed by the measurement surface, a radius of 0.466" (11.84 mm) measured from the lens side of the tab to the sensing surface and a sensing surface of 0.250" (6.35 mm) in diameter forming a 10° cone. E_{E(APT)} is not necessarily uniform within the measured area.

OP230 Series Obsolete (OP231W)



Performance

OP231, OP232, OP233 (including "W" devices)



General Note

TT Electronics reserves the right to make changes in product specification without notice or liability. All information is subject to TT Electronics' own data and is considered accurate at time of going to print.

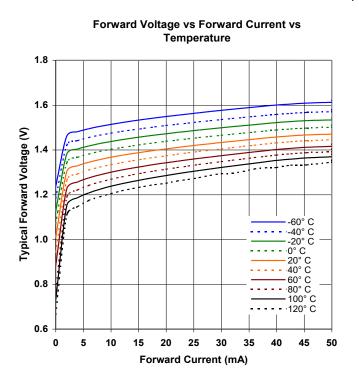
Distance (inches)

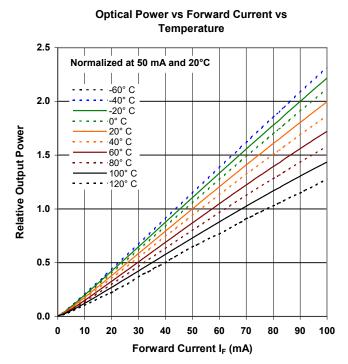
Angular Displacement (Degrees)

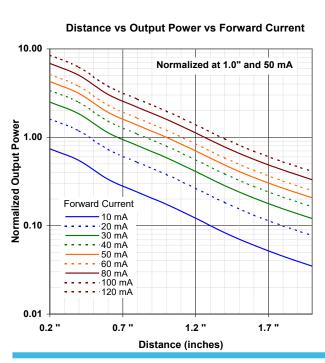
OP230 Series Obsolete (OP231W)

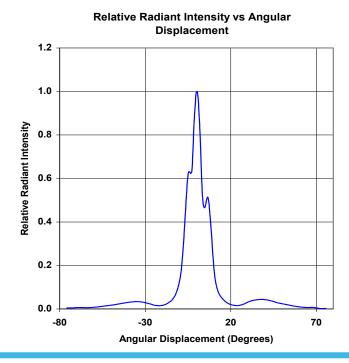


Performance OP234, OP234W









General Note

TT Electronics reserves the right to make changes in product specification without notice or liability. All information is subject to TT Electronics' own data and is considered accurate at time of going to print.

OP230 Series
Obsolete (OP231W)



Performance OP235, OP235W

